



Web Resources



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Size Table

Metric	EIA
3216	1206

Absolute Maximum Ratings

Continuous	MLN Series	Units
Steady State Applied Voltage:		
DC Voltage Range (V _{M(DC)})	5.5 - 18	V
Operating Ambient Temperature Range (T _A)	-40 to +125	°C
Storage Temperature Range (T _{STG})	-40 to +150	°C

For ratings of individual members of a series, see device ratings and specifications table

Description

The MLN SurgeArrayTM Suppressor is designed to help protect components from transient voltages that exist at the circuit board level. This device provides four independent suppressors in a single leadless chip in order to reduce part count and placement time as well as save space on printed circuit boards.

SurgeArray™ Suppressor are intended to suppress ESD, EFT and other transients in order to protect integrated circuits or other sensitive components operating at any voltage up to 18VDC. SurgeArray™ Suppressor are rated to the IEC 61000-4-2 human body model ESD to help products attain EMC compliance. The array offers excellent isolation and low crosstalk between sections.

The inherent capacitance of the SurgeArray[™] Suppressor permits it to function as a filter/suppressor, thereby replacing separate Zener/capacitor combinations.

The MLN array is manufactured using the Littelfuse Multilayer technology process and is similar to the Littelfuse ML and MLE Series of discrete leadless chips.

Features & Benefits

- RoHS Compliant
- Four individual devices in one chip
- ESD rated to IEC 61000-4-2 (Level 4)
- AC characterized for impedance and capacitance
- Low adjacent channel crosstalk, -55dB at 10MHz (Typ)

- Low leakage
- Operating voltage up to 18VM(DC)
- -40°C to 125°C operating temp range
- Low-profile, PCMCIA compatible

Applications

- Data, Diagnostic I/O Ports
- Analog Signal/Sensor Lines
- Portable/Hand-Held Products
- Mobile Communications/ Cellular Phones
- Computer/DSP Products
- Industrial Instruments Including Medical



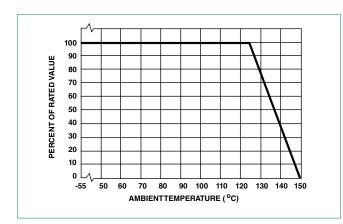
Device Ratings and Specifications Any Single Section

Maximum Ratings (125°C)		Specifications (25°C)									
Part Number	Maximum Continuous Working Voltage	Maximum Non- repetitive Surge Current (8/20µs)	Maximum Non-repetitive Surge Energy (10/1000µs)	petitive Clamping Voltage (at Energy Noted 8/20us) Voltage (Note1) Voltage (Note1)		Typical ESD Supression		DC Test	Capacitance at 1 MHz (1V p-p)		
	V _{M(DC)}	I _{TM}	TM C	V _c		(Note 2) (Note 8kV Contact 15kV A		VN(DC)	VN(DC)	•	te 4) C
	M(DC)	I IVI		Peak	Clamp	Peak	Min	Max	TYP	MAX	
	(V)	(A)	(J)	(V)	(V)	(V)	(V)	(V)	(V)	(pF)	(pF)
V5.5MLN41206	5.5	30	0.10	15.5 at 2A	60	35	45	7.10	10.8	430	520
V9MLN41206	9.0	30	0.10	23.0 at 2A	95	50	75	11.0	16.0	250	300
V14MLN41206	14.0	30	0.10	30.0 at 2A	110	55	85	15.9	20.3	140	175
V18MLN41206	18.0	30	0.10	40.0 at 2A	165	63	100	22.0	28.0	100	125
V18MLN41206L	18.0	30	0.05	50.0 at 1A	200	95	130	25.0	35.0	45	75

Notes:

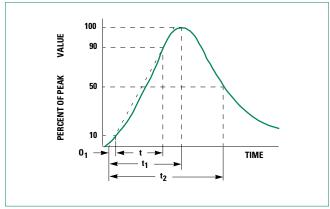
- 1. Tested to IEC61000-4-2 Human Body Model (HBM) discharge test circuit.
- Direct discharge to device terminals (IEC preffered test method).
 Corona discharge through air (represents actual ESD event)
- 4. Capacitance may be customized, contact Sales.
- 5. The typical capacitance rating is the discrete component test result.

Fig. 1 Peak Current and Energy Derating Curve



For applications exceeding 125°C ambient temperature, the peak surge current and energy ratings must be

Fig. 2 Peak Pulse Current Test Waveform for Clamping **Voltage**



0, = Virtual Origin of Wave = Time from 10% to 90% of Peak $T_1 = Rise Time = 1.25 x T$

T. = Decay Time

(Impulse Duration)

Example:

For an 8/20 µs Current Waveform: $8\mu s = T_s = Rise Time$ $20\mu s = T_2 = Virtual Time to Half Value$

Typical Performance Curves

Fig. 3 Equivalent Series Resistance

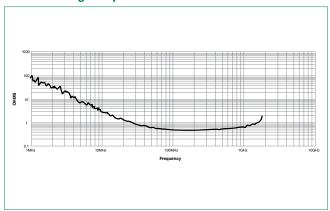
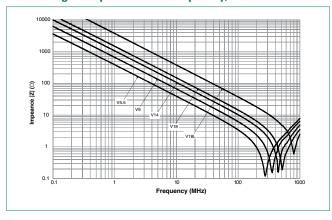


Fig. 4 Impedance vs Frequency, 1206 Size





Typical Performance Curves (continued)

Fig. 5 Nominal Voltage Stability to IEC 1000-4-2 (8kV Contact Method, One Section)

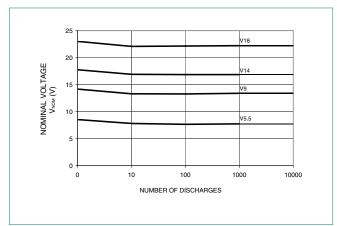


Fig. 6 1206 Size Pulse Rating for Long Duration Surges (Any Single Section)

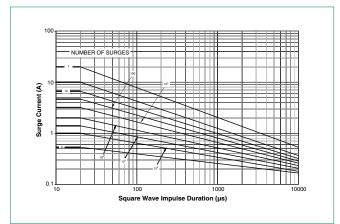


Fig. 7 V-I Characteristic, 1206 size

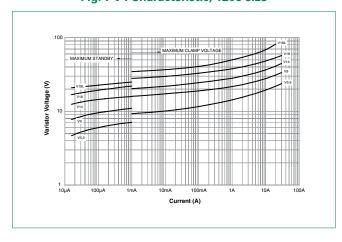


Fig. 8 Capacitance vs Frequency, 1206 Size

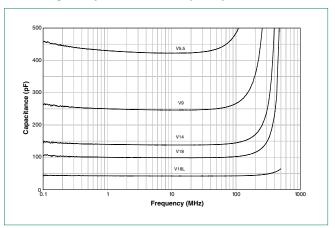
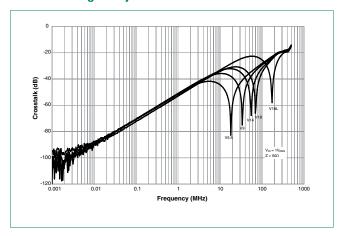


Fig. 9 Adjacent Channel Crosstalk





Lead (Pb) Soldering Recommendations

The principal techniques used for the soldering of components in surface mount technology are IR Re-flow and Wave soldering. Typical profiles are shown on the right.

The recommended solder for the MLN suppressor is a 62/36/2 (Sn/Pb/Ag), 60/40 (Sn/Pb) or 63/37 (Sn/Pb). Littelfuse also recommends an RMA solder flux.

Wave soldering is the most strenuous of the processes. To avoid the possibility of generating stresses due to thermal shock, a preheat stage in the soldering process is recommended, and the peak temperature of the solder process should be rigidly controlled.

When using a reflow process, care should be taken to ensure that the MLN chip is not subjected to a thermal gradient steeper than 4 degrees per second; the ideal gradient being 2 degrees per second. During the soldering process, preheating to within 100 degrees of the solder's peak temperature is essential to minimize thermal shock.

Once the soldering process has been completed, it is still necessary to ensure that any further thermal shocks are avoided. One possible cause of thermal shock is hot printed circuit boards being removed from the solder process and subjected to cleaning solvents at room temperature. The boards must be allowed to cool gradually to less than 50°C before cleaning.

Fig. 10 Reflow Solder Profile

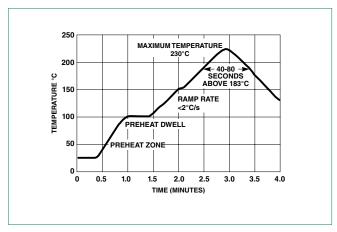
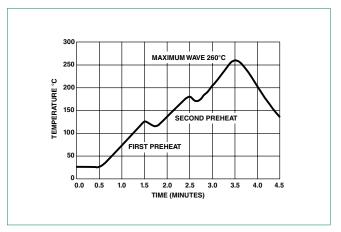
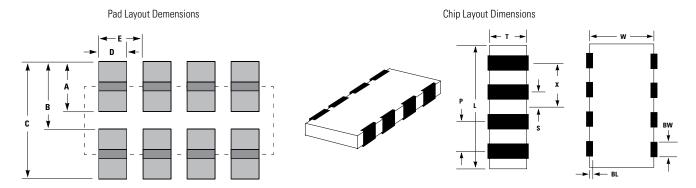


Fig. 11 Wave Solder Profile



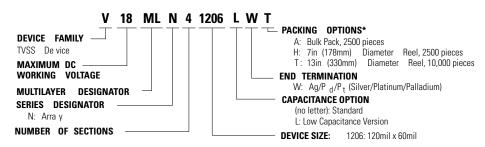


Product Dimensions (mm)



Di	1206 Size					
Dimension	IN	MM				
Α	0.035	0.890				
В	0.065	1.650				
С	0.100	2.540				
D	0.018	0.460				
E	0.030	0.790				
L	0.126 -/+0.008	3.200 -/+0.200				
W	0.063 -/+0.008	1.600 -/+0.200				
Т	0.053 Max	1.350 Max				
BW	0.016 -/+0.004	0.410 -/+0.100				
BL	0.007 +0.01/- 0.002	0.180 +0.25/-0.050				
P	0.030 Ref	0.760 Ref				
Χ	0.045 -/+0.004	1.140 -/+0.100				
S	0.015 -/+0.004	0.380 -/+0.100				

Part Numbering System



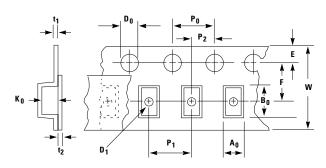
Packaging*

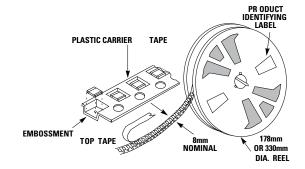
	Quantity			
Device Size	13" Inch Reel ("T" Option)	7" Inch Reel ("H" Option)	Bulk Pack ("A" Option)	
1206	10,000	2,500	2,500	

^{*(}Packaging) It is recommended that parts be kept in the sealed bag provided and that parts be used as soon as possible when removed from bags.



Tape and Reel Specifications





Symbol	Description	Dimensions in Millimeters
A _o	Width of Cavity	Dependent on Chip Size to Minimize Rotation.
B _o	Length of Cavity	Dependent on Chip Size to Minimize Rotation.
K _o	Depth of Cavity	Dependent on Chip Size to Minimize Rotation.
W	Width of Tape	8 -/+0.2
F	Distance Between Drive Hole Centers and Cavity Centers	3.5 -/+0.5
E	Distance Between Drive Hole Centers and Tape Edge	1.75 -/+0.1
P ₁	Distance Between Cavity Center	4 -/+0.1
P ₂	Axial Distance Between Drive Hole Centers and Cavity Centers	2 -/+0.1
P_{o}	Axial Distance Between Drive Hole Centers	4 -/+0.1
D _o	Drive Hole Diameter	1.55 -/+0.05
D ₁	Diameter of Cavity Piercing	1.05 -/+0.05
T ₁	Embossed Tape Thickness	0.3 Max
T ₂	Top Tape Thickness	0.1 Max

Notes:



Conforms to EIA-481-1, Revision A

[•] Can be supplied to IEC publication 286-3